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HEWLETT® PACKARD

Low Current, High Performance NPN Silicon Bipolar Transistor

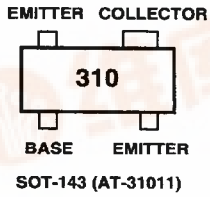
Technical Data

AT-31011
AT-31033

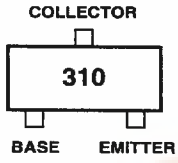
Features

- **High Performance Bipolar Transistor Optimized for Low Current, Low Voltage Operation**
- **900 MHz Performance:**
  AT-31011: 0.9 dB NF, 13 dB G_A
  AT-31033: 0.9 dB NF, 11 dB G_A
- **Characterized for End-Of-Life Battery Use (2.7 V)**
- **SOT-143 SMT Plastic Package**
- **Tape-And-Reel Packaging Option Available**[1]

Outline Drawing



SOT-143 (AT-31011)



SOT-23 (AT-31033)

Note:
1. Refer to "Tape-and-Reel Packaging for Semiconductor Devices"

Description

Hewlett-Packard's AT-31011 and AT-31033 are high performance NPN bipolar transistors that have been optimized for operation at low voltages, making them ideal for use in battery powered applications in wireless markets. The AT-31033 uses the 3 lead SOT-23, while the AT-31011 places the same die in the higher performance 4 lead SOT-143. Both packages are industry standards compatible with high volume surface mount assembly techniques.

The 3.2 micron emitter-to-emitter pitch and reduced parasitic design of these transistors yields extremely high performance products that can perform a multiplicity of tasks. The 10 emitter finger interdigitated geometry yields an extremely fast transistor with low operating currents and reasonable impedances.

Optimized performance at 2.7 V makes these devices ideal for use in 900 MHz, 1.9 GHz, and 2.4 GHz battery operated systems as an LNA, gain stage, buffer, oscillator, or active mixer. Applications include cellular and PCS handsets as well as Industrial-Scientific-Medical systems. Typical amplifier designs at 900 MHz yield 1.3 dB noise figures with 11 dB or more associated gain at a 2.7 V, 1 mA bias. Moderate output power capability (+9 dBm P_{1dB}) coupled with an excellent noise figure yields high dynamic range for a microcurrent device. High gain capability at 1 V, 1 mA makes these devices a good fit for 900 MHz pager applications.

The AT-3 series bipolar transistors are fabricated using an optimized version of Hewlett-Packard's 10 GHz f_T, 30 GHz f_{max} Self-Aligned-Transistor (SAT) process. The die are nitride passivated for surface protection. Excellent device uniformity, performance and reliability are produced by the use of ion-implantation, self-alignment techniques, and gold metalization in the fabrication of these devices.

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AT-31011, AT-31033 Absolute Maximum Ratings

Symbol	Parameter	Units	Absolute Maximum[1]
V_{EBO}	Emitter-Base Voltage	V	1.5
V_{CBO}	Collector-Base Voltage	V	11
V_{CEO}	Collector-Emitter Voltage	V	5.5
I_C	Collector Current	mA	16
P_T	Power Dissipation[2,3]	mW	150
T_j	Junction Temperature	°C	150
T_{STG}	Storage Temperature	°C	-65 to 150

Thermal Resistance[2]:
θ_{jc} = 550°C/W

Notes:
1. Operation of this device above any one of these parameters may cause permanent damage.
2. $T_{Mounting\ Surface}$ = 25°C.
3. Derate at 1.82 mW/°C for T_C > 67.5°C.

Electrical Specifications, T_A = 25°C

Symbol	Parameters and Test Conditions		Units	AT-31011			AT-31033		
				Min	Typ	Max	Min	Typ	Max
NF	Noise Figure V_{CE} = 2.7 V, I_C = 1 mA	f = 0.9 GHz	dB		0.9[1]	1.2[1]		0.9[2]	1.2[2]
G_A	Associated Gain V_{CE} = 2.7 V, I_C = 1 mA	f = 0.9 GHz	dB	11[1]	13[1]		9[2]	11[2]	
h_{FE}	Forward Current Transfer Ratio	V_{CE} = 2.7 V I_C = 1 mA	-	70		300	70		300
I_{CBO}	Collector Cutoff Current	V_{CB} = 3 V	μA		0.05	0.2		0.05	0.2
I_{EBO}	Emitter Cutoff Current	V_{EB} = 1 V	μA		0.1	1.5		0.1	1.5

Notes:
1. Test circuit B, Figure 1. Numbers reflect device performance de-embedded from circuit losses. Input loss = 0.4 dB; output loss = 0.4 dB.
2. Test circuit A, Figure 1. Numbers reflect device performance de-embedded from circuit losses. Input loss = 0.4 dB; output loss = 0.4 dB.

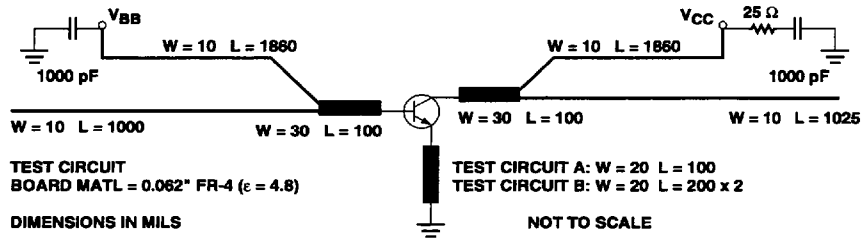


Figure 1. Test Circuit for Noise Figure and Associated Gain. This Circuit is a Compromise Match Between Best Noise Figure, Best Gain, Stability, a Practical, Synthesizable Match, and a Circuit Capable of Matching Both the AT-305 and AT-310 Geometries.

Characterization Information, T_A = 25° C

Symbol	Parameters and Test Conditions		Units	AT-31011 Typ	AT-31033 Typ
P_{1dB}	Power at 1 dB Gain Compression (opt tuning) V_{CE} = 2.7 V, I_C = 10 mA	f = 0.9 GHz	dBm	9	9
G_{1dB}	Gain at 1 dB Gain Compression (opt tuning) V_{CE} = 2.7 V, I_C = 10 mA	f = 0.9 GHz	dB	15	13
IP_3	Output Third Order Intercept Point, V_{CE} = 2.7 V, I_C = 10 mA (opt tuning)	f = 0.9 GHz	dBm	20	20
$\|S_{21}\|_E^2$	Gain in 50 Ω System; V_{CE} = 2.7 V, I_C = 1 mA	f = 0.9 GHz	dB	10	9
C_{CB}	Collector-Base Capacitance	V_{CB} = 3V, f = 1 MHz	pF	0.04	0.04

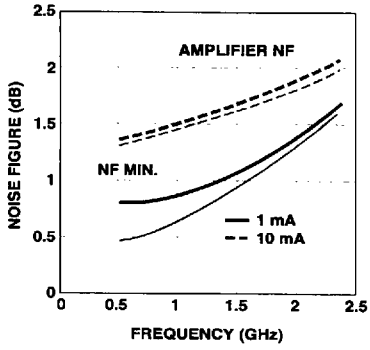


Figure 2. AT-31011 and AT-31033 Minimum Noise Figure and Amplifier NF[1] vs. Frequency and Current at V_{CE} = 2.7 V.

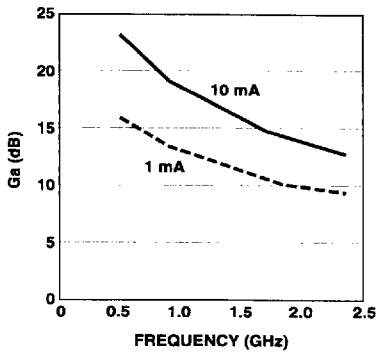


Figure 3. AT-31011 Associated Gain at Optimum Noise Match vs. Frequency and Current at V_{CE} = 2.7 V.

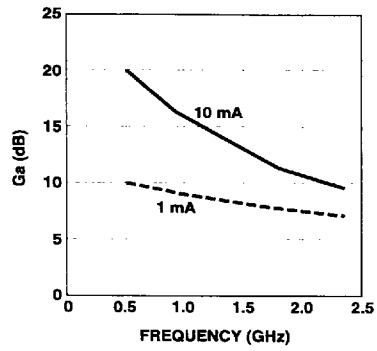


Figure 4. AT-33033 Associated Gain at Optimum Noise Match vs. Frequency and Current at V_{CE} = 2.7 V.

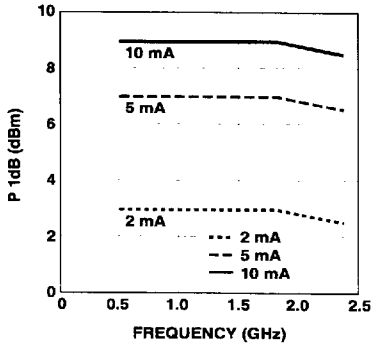


Figure 5. AT-31011 and AT-31033 Power at 1 dB Gain Compression vs. Frequency and Current at V_{CE} = 2.7 V.

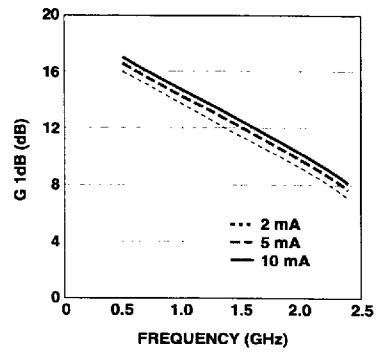


Figure 6. AT-31011 1 dB Compressed Gain vs. Frequency and Current at V_{CE} = 2.7 V.

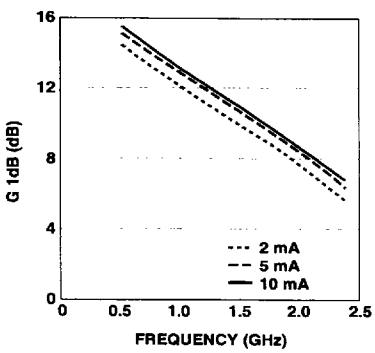


Figure 7. AT-33033 1 dB Compressed Gain vs. Frequency and Current at V_{CE} = 2.7 V.

Note:

1. Amplifier NF represents the noise figure which can be expected in a real circuit representing reasonable reflection coefficients and including circuit losses.

AT-31011, AT-31033 Typical Performance

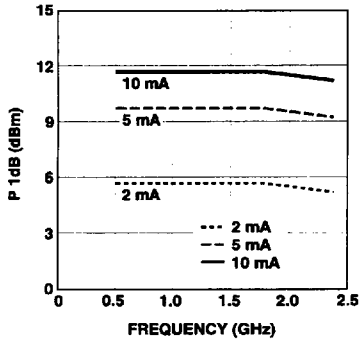


Figure 8. AT-31011 and AT-31033 Power at 1 dB Gain Compression vs. Frequency and Current at V_{CE} = 5 V.

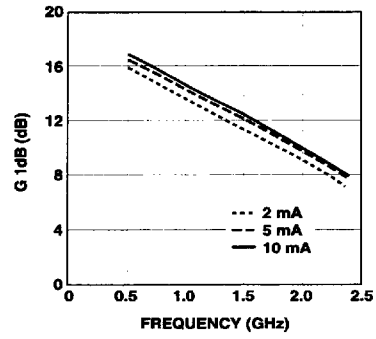


Figure 9. AT-31011 1 dB Compressed Gain vs. Frequency and Current at V_{CE} = 5 V.

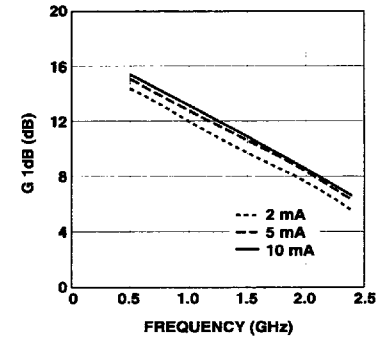


Figure 10. AT-31033 1 dB Compressed Gain vs. Frequency and Current at V_{CE} = 5 V.

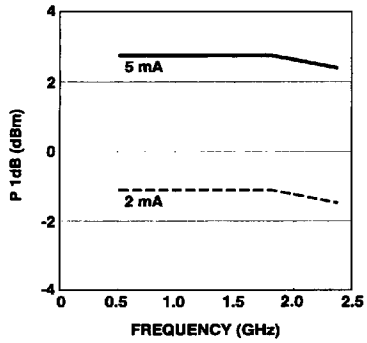


Figure 11. AT-31011 and AT-31033 Power at 1 dB Gain Compression vs. Frequency and Current at V_{CE} = 1 V.

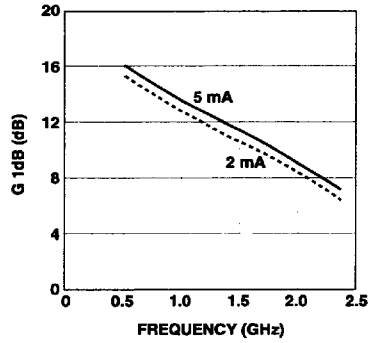


Figure 12. AT-31011 1 dB Compressed Gain vs. Frequency and Current at V_{CE} = 1 V.

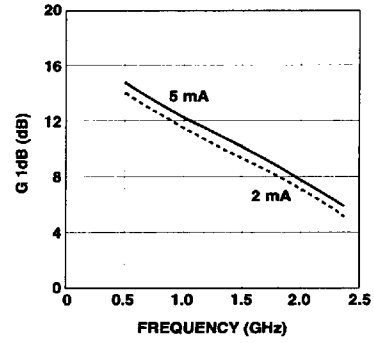


Figure 13. AT-31033 1 dB Compressed Gain vs. Frequency and Current at V_{CE} = 1 V.

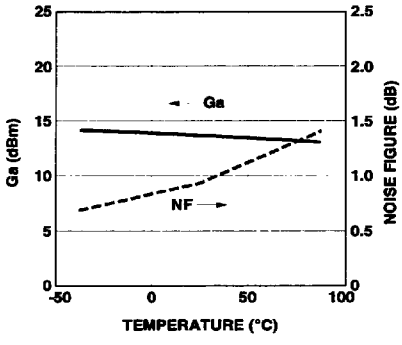


Figure 14. AT-31011 Noise Figure and Associated Gain at V_{CE} = 2.7 V, I_C = 1 mA vs. Temperature in Test Circuit, Figure 1. (Circuit Losses De-embedded)

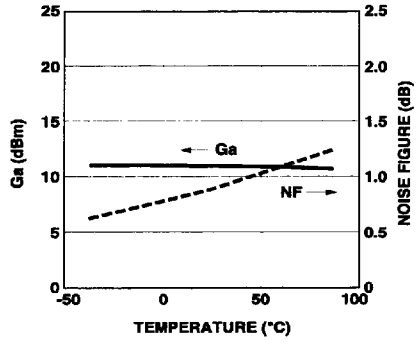


Figure 15. AT-31033 Noise Figure and Associated Gain at V_{CE} = 2.7 V, I_C = 1 mA vs. Temperature in Test Circuit, Figure 1. (Circuit Losses De-embedded)

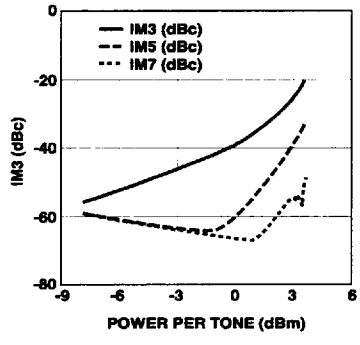


Figure 16. AT-31011 and AT-31033 Intermodulation Products vs. Output Power at V_{CE} = 2.7 V, I_C = 10 mA, 900 MHz with Optimal Tuning.

AT-31011 Typical Scattering Parameters, V_{CE} = 1 V, I_C = 1 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.95	-8	11.12	3.60	174	-37.91	0.01	85	0.999	-3
0.5	0.92	-34	10.58	3.38	150	-24.67	0.06	68	0.94	-15
0.9	0.81	-60	9.74	3.07	130	-20.67	0.09	53	0.89	-25
1.0	0.79	-66	9.33	2.93	125	-20.03	0.10	50	0.88	-27
1.5	0.66	-94	8.02	2.52	104	-18.34	0.12	36	0.80	-36
1.8	0.60	-110	7.18	2.28	93	-17.95	0.13	30	0.76	-40
2.0	0.57	-119	6.76	2.18	87	-17.73	0.13	27	0.74	-42
2.4	0.51	-139	5.56	1.90	74	-17.69	0.13	22	0.71	-46
3.0	0.45	-167	4.22	1.63	57	-17.95	0.13	19	0.67	-51
4.0	0.45	153	2.30	1.30	36	-18.33	0.12	22	0.64	-62
5.0	0.49	120	0.73	1.09	17	-17.33	0.14	32	0.62	-72

AT-31011 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 1 V, I_C = 1 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT}		R_n
		Mag	Ang	
0.5[2]	0.5	0.90	13	0.85
0.9	0.6	0.85	29	0.73
1.8	1.1	0.68	67	0.46
2.4	1.6	0.55	98	0.28

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

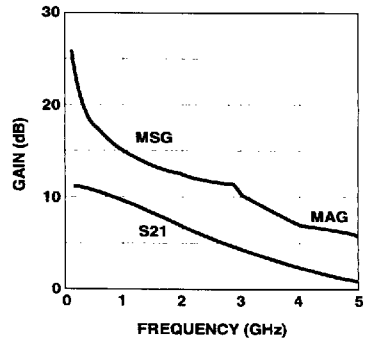


Figure 17. AT-31011 Gains vs. Frequency at V_{CE} = 1 V, I_C = 1 mA.

AT-31033 Typical Scattering Parameters, V_{CE} = 1 V, I_C = 1 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.94	-7	11.16	3.61	173	-35.95	0.02	85	0.999	-3
0.5	0.87	-34	10.37	3.30	144	-22.84	0.07	68	0.92	-17
0.9	0.70	-58	9.17	2.87	121	-19.06	0.11	56	0.85	-27
1.0	0.66	-64	8.69	2.72	115	-18.49	0.12	53	0.83	-29
1.5	0.46	-90	7.11	2.27	92	-16.94	0.14	45	0.74	-37
1.8	0.36	-106	6.16	2.03	81	-16.40	0.15	43	0.70	-40
2.0	0.31	-117	5.66	1.92	74	-16.06	0.16	42	0.68	-42
2.4	0.22	-143	4.48	1.67	62	-15.50	0.17	42	0.66	-45
3.0	0.16	166	3.19	1.44	46	-14.34	0.19	44	0.63	-50
4.0	0.23	101	1.39	1.17	25	-11.85	0.26	46	0.60	-62
5.0	0.33	67	0.05	1.01	9	-9.11	0.35	41	0.56	-77

AT-31033 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 1 V, I_C = 1 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT}		R_n
		Mag	Ang	
0.5[2]	0.5	0.90	12	0.70
0.9	0.6	0.82	28	0.60
1.8	1.1	0.57	68	0.38
2.4	1.6	0.41	100	0.22

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

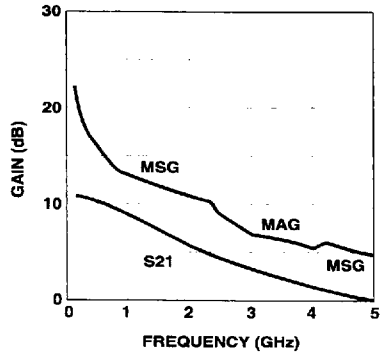


Figure 18. AT-31033 Gains vs. Frequency at V_{CE} = 1 V, I_C = 1 mA.

AT-31011 Typical Scattering Parameters, V_{CE} = 2.7 V, I_C = 1 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11} Mag	S_{11} Ang	S_{21} dB	S_{21} Mag	S_{21} Ang	S_{12} dB	S_{12} Mag	S_{12} Ang	S_{22} Mag	S_{22} Ang
0.1	0.96	-7	11.11	3.59	174	-39.92	0.01	86	0.999	-2
0.5	0.93	-32	10.66	3.41	152	-26.43	0.05	69	0.95	-13
0.9	0.83	-56	9.90	3.13	132	-22.32	0.08	55	0.91	-22
1.0	0.81	-61	9.53	2.99	128	-21.66	0.08	53	0.90	-24
1.5	0.68	-89	8.32	2.61	107	-19.90	0.10	40	0.84	-32
1.8	0.62	-104	7.52	2.38	96	-19.46	0.11	34	0.80	-36
2.0	0.58	-113	7.15	2.28	90	-19.24	0.11	31	0.78	-38
2.4	0.52	-133	5.98	1.99	77	-19.15	0.11	27	0.75	-42
3.0	0.45	-160	4.65	1.71	61	-19.37	0.11	25	0.72	-46
4.0	0.43	158	2.75	1.37	39	-19.60	0.10	29	0.69	-56
5.0	0.46	123	1.16	1.14	20	-18.16	0.12	41	0.68	-66

AT-31011 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 2.7 V, I_C = 1 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT} Mag	Γ_{OPT} Ang	R_n
0.5[2]	0.5	0.92	13	0.85
0.9	0.6	0.85	29	0.73
1.8	1.1	0.68	67	0.46
2.4	1.6	0.55	98	0.28

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

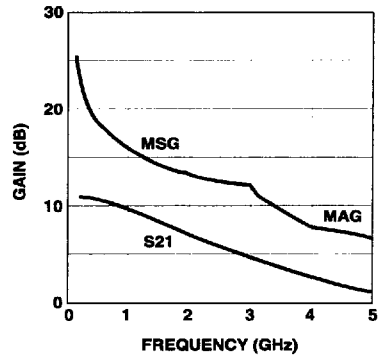


Figure 19. AT-31011 Gains vs. Frequency at V_{CE} = 2.7 V, I_C = 1 mA.

AT-31033 Typical Scattering Parameters, V_{CE} = 2.7 V, I_C = 1 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11} Mag	S_{11} Ang	S_{21} dB	S_{21} Mag	S_{21} Ang	S_{12} dB	S_{12} Mag	S_{12} Ang	S_{22} Mag	S_{22} Ang
0.1	0.94	-7	11.07	3.58	173	-37.44	0.01	86	0.999	-3
0.5	0.89	-32	10.35	3.29	146	-24.11	0.06	70	0.94	-15
0.9	0.72	-54	9.27	2.91	123	-20.27	0.10	58	0.87	-25
1.0	0.69	-59	8.80	2.76	118	-19.65	0.10	56	0.86	-26
1.5	0.48	-83	7.32	2.32	95	-18.01	0.13	48	0.78	-33
1.8	0.38	-97	6.39	2.09	84	-17.43	0.13	46	0.74	-36
2.0	0.33	-107	5.91	1.97	77	-17.07	0.14	45	0.72	-38
2.4	0.23	-130	4.73	1.72	65	-16.46	0.15	46	0.70	-41
3.0	0.14	-178	3.43	1.48	49	-15.25	0.17	48	0.67	-46
4.0	0.19	103	1.62	1.21	28	-12.62	0.23	51	0.65	-57
5.0	0.30	67	0.25	1.03	12	-9.72	0.33	47	0.63	-71

AT-31033 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 2.7 V, I_C = 1 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT} Mag	Γ_{OPT} Ang	R_n
0.5[2]	0.5	0.90	12	0.70
0.9	0.6	0.82	28	0.60
1.8	1.1	0.57	68	0.38
2.4	1.6	0.41	100	0.22

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

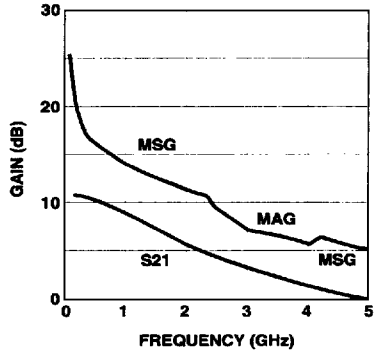


Figure 20. AT-31033 Gains vs. Frequency at V_{CE} = 2.7 V, I_C = 1 mA.

AT-31011 Typical Scattering Parameters, V_{CE} = 2.7 V, I_C = 10 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.74	-23	27.42	23.49	161	-41.00	0.01	77	0.95	-9
0.5	0.46	-85	22.65	13.57	116	-30.64	0.03	59	0.68	-24
0.9	0.32	-121	18.73	8.64	97	-27.55	0.04	59	0.59	-27
1.0	0.30	-128	17.91	7.86	93	-27.05	0.04	59	0.58	-27
1.5	0.25	-161	14.77	5.48	79	-24.48	0.06	61	0.55	-30
1.8	0.25	-177	13.29	4.62	72	-23.26	0.07	61	0.54	-32
2.0	0.24	174	12.42	4.18	68	-22.51	0.07	61	0.53	-33
2.4	0.25	157	10.97	3.54	60	-21.12	0.09	59	0.53	-36
3.0	0.27	138	9.11	2.86	49	-19.31	0.11	58	0.52	-40
4.0	0.31	113	6.86	2.20	33	-16.88	0.14	54	0.51	-50
5.0	0.37	94	5.19	1.82	17	-14.75	0.18	48	0.50	-59

AT-31011 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 2.7 V, I_C = 10 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT}		R_n
		Mag	Ang	
0.5[2]	1.3	0.45	11	0.55
0.9	1.4	0.37	33	0.46
1.8	1.7	0.25	86	0.29
2.4	2.0	0.18	129	0.18

Notes:

1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

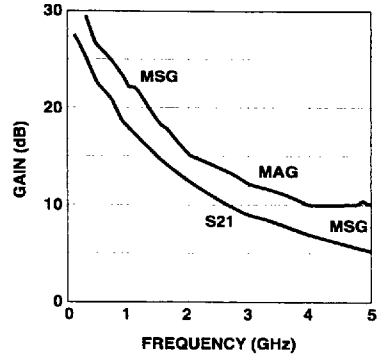


Figure 21. AT-31011 Gains vs. Frequency at V_{CE} = 2.7 V, I_C = 10 mA.

AT-31033 Typical Scattering Parameters, V_{CE} = 2.7 V, I_C = 10 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.72	-21	26.80	21.87	154	-38.46	0.01	80	0.92	-10
0.5	0.33	-49	19.93	9.92	106	-27.31	0.04	73	0.66	-20
0.9	0.19	-47	15.51	5.96	88	-22.90	0.07	72	0.61	-22
1.0	0.17	-46	14.66	5.41	85	-22.03	0.08	72	0.60	-23
1.5	0.11	-28	11.44	3.73	72	-18.74	0.12	69	0.59	-27
1.8	0.10	-14	9.99	3.16	66	-17.26	0.14	67	0.58	-30
2.0	0.10	-6	9.15	2.87	62	-16.40	0.15	65	0.58	-32
2.4	0.10	9	7.78	2.45	54	-14.88	0.18	62	0.57	-35
3.0	0.12	23	6.16	2.03	43	-12.99	0.22	57	0.55	-41
4.0	0.15	34	4.30	1.64	27	-10.49	0.30	48	0.52	-53
5.0	0.20	36	3.01	1.41	12	-8.53	0.37	38	0.48	-65

AT-31033 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 2.7 V, I_C = 10 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT}		R_n
		Mag	Ang	
0.5[2]	1.3	0.42	10	0.38
0.9	1.4	0.31	30	0.34
I.8	1.7	0.16	80	0.23
2.4	2.0	0.08	118	0.17

Notes:

1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

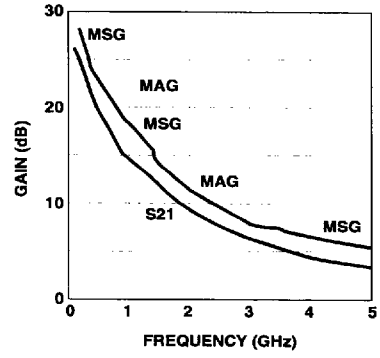


Figure 22. AT-31033 Gains vs. Frequency at V_{CE} = 2.7 V, I_C = 10 mA.

AT-31011 Typical Scattering Parameters, V_{CE} = 5 V, I_C = 1 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11} Mag	S_{11} Ang	S_{21} dB	S_{21} Mag	S_{21} Ang	S_{12} dB	S_{12} Mag	S_{12} Ang	S_{22} Mag	S_{22} Ang
0.1	0.96	-7	11.10	3.59	174	-40.35	0.01	84	0.999	-2
0.5	0.94	-31	10.67	3.41	153	-26.95	0.04	69	0.96	-13
0.9	0.83	-54	9.93	3.14	133	-22.80	0.07	56	0.92	-22
1.0	0.81	-60	9.57	3.01	129	-22.18	0.08	53	0.91	-23
1.5	0.68	-86	8.41	2.63	108	-20.33	0.10	41	0.85	-31
1.8	0.62	-101	7.62	2.40	97	-19.85	0.10	35	0.81	-35
2.0	0.58	-110	7.27	2.31	91	-19.64	0.10	32	0.79	-37
2.4	0.52	-129	6.10	2.02	78	-19.50	0.11	28	0.76	-41
3.0	0.44	-157	4.78	1.73	62	-19.68	0.10	26	0.73	-45
4.0	0.42	161	2.90	1.40	40	-19.86	0.10	31	0.70	-55
5.0	0.45	125	1.33	1.17	21	-18.35	0.12	43	0.70	-65

AT-31011 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 5 V, I_C = 1 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT} Mag	Γ_{OPT} Ang	R_n
0.5[2]	0.5	0.92	13	0.85
0.9	0.6	0.85	29	0.73
1.8	1.1	0.68	67	0.46
2.4	1.6	0.55	98	0.28

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

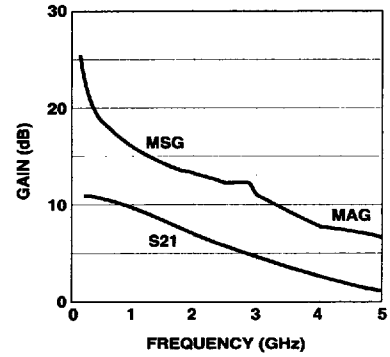


Figure 23. AT-31011 Gains vs. Frequency at V_{CE} = 5 V, I_C = 1 mA.

AT-31033 Typical Scattering Parameters, V_{CE} = 5 V, I_C = 1 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11} Mag	S_{11} Ang	S_{21} dB	S_{21} Mag	S_{21} Ang	S_{12} dB	S_{12} Mag	S_{12} Ang	S_{22} Mag	S_{22} Ang
0.1	0.95	-7	10.93	3.52	173	-37.78	0.01	85	0.999	-3
0.5	0.89	-31	10.24	3.25	147	-24.43	0.06	70	0.94	-15
0.9	0.73	-52	9.20	2.88	124	-20.49	0.09	59	0.88	-24
1.0	0.70	-57	8.75	2.74	119	-19.91	0.10	57	0.87	-26
1.5	0.49	-80	7.30	2.32	96	-18.15	0.12	49	0.79	-32
1.8	0.39	-93	6.41	2.09	85	-17.54	0.13	47	0.75	-36
2.0	0.34	-102	5.93	1.98	78	-17.19	0.14	46	0.73	-37
2.4	0.23	-122	4.77	1.73	66	-16.55	0.15	46	0.71	-40
3.0	0.13	-166	3.49	1.49	50	-15.35	0.17	49	0.68	-45
4.0	0.17	107	1.71	1.22	29	-12.83	0.23	51	0.66	-56
5.0	0.28	68	0.32	1.04	12	-9.96	0.32	48	0.64	-69

AT-31033 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 5 V, I_C = 1 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT} Mag	Γ_{OPT} Ang	R_n
0.5[2]	0.5	0.90	12	0.70
0.9	0.6	0.82	28	0.60
1.8	1.1	0.57	68	0.38
2.4	1.6	0.41	100	0.22

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

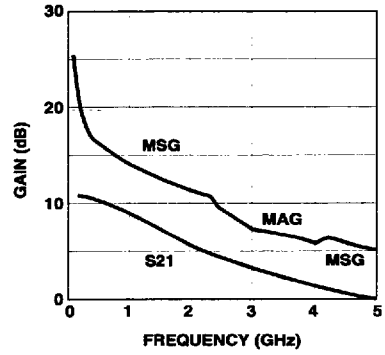


Figure 24. AT-31033 Gains vs. Frequency at V_{CE} = 5 V, I_C = 1 mA.

AT-31011 Typical Scattering Parameters, V_{CE} = 5 V, I_C = 10 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.77	-21	27.41	23.46	162	-41.49	0.01	80	0.95	-8
0.5	0.48	-77	22.97	14.07	118	-30.66	0.03	61	0.70	-24
0.9	0.32	-112	19.14	9.06	98	-27.77	0.04	59	0.61	-27
1.0	0.30	-119	18.34	8.26	95	-27.11	0.04	60	0.59	-27
1.5	0.23	-151	15.23	5.78	80	-24.56	0.06	60	0.56	-29
1.8	0.22	-168	13.75	4.87	73	-23.37	0.07	60	0.55	-31
2.0	0.21	-178	12.91	4.42	69	-22.62	0.07	60	0.55	-32
2.4	0.21	163	11.46	3.74	61	-21.25	0.09	59	0.54	-36
3.0	0.23	142	9.60	3.02	50	-19.45	0.11	58	0.53	-39
4.0	0.27	116	7.36	2.33	34	-17.08	0.14	54	0.52	-48
5.0	0.33	96	5.70	1.93	19	-14.97	0.18	48	0.51	-58

AT-31011 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 5 V, I_C = 10 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT}		R_n
		Mag	Ang	
0.5[2]	1.3	0.45	11	0.55
0.9	1.4	0.37	33	0.46
1.8	1.7	0.25	86	0.29
2.4	2.0	0.18	129	0.18

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unachievable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

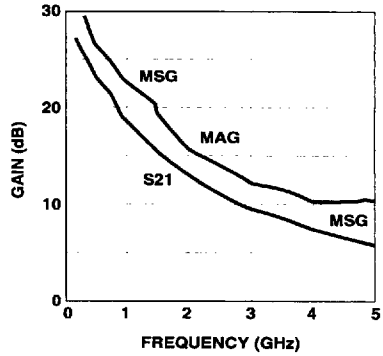


Figure 25. AT-31011 Gains vs. Frequency at V_{CE} = 5 V, I_C = 10 mA.

AT-31033 Typical Scattering Parameters, V_{CE} = 5 V, I_C = 10 mA, Common Emitter, Z_O = 50 Ω

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.75	-19	26.79	21.84	155	-38.82	0.01	79	0.92	-10
0.5	0.37	-45	20.17	10.20	107	-27.39	0.04	73	0.67	-20
0.9	0.23	-42	15.79	6.16	90	-23.00	0.07	72	0.62	-22
1.0	0.21	-42	14.94	5.58	86	-22.11	0.08	72	0.61	-23
1.5	0.15	-30	11.75	3.87	73	-18.86	0.11	69	0.60	-27
1.8	0.14	-21	10.30	3.27	67	-17.37	0.14	66	0.59	-29
2.0	0.13	-17	9.47	2.97	63	-16.51	0.15	65	0.58	-31
2.4	0.13	-7	8.08	2.54	55	-15.00	0.18	62	0.57	-35
3.0	0.13	3	6.47	2.11	45	-13.14	0.22	57	0.56	-41
4.0	0.14	19	4.61	1.7	29	-10.67	0.29	48	0.53	-52
5.0	0.18	28	3.33	1.47	14	-8.73	0.37	38	0.49	-64

AT-31033 Typical Noise Parameters,

Common Emitter, Z_O = 50 Ω, 5 V, I_C = 10 mA

Freq GHz	F_{min}[1] dB	Γ_{OPT}		R_n
		Mag	Ang	-
0.5[2]	1.3	0.42	10	0.38
0.9	1.4	0.31	30	0.34
1.8	1.7	0.16	80	0.23
2.4	2.0	0.08	118	0.17

Notes:
1. Matching constraints may make F_{min} values associated with high $|\Gamma_{OPT}|$ values unacheivable in physical circuits. See Figure 2 for expected performance.
2. 0.5 GHz noise parameter values are extrapolated, not measured.

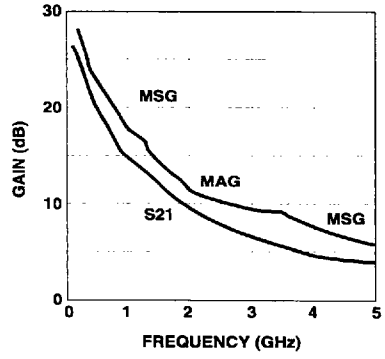


Figure 26. AT-31033 Gains vs. Frequency at V_{CE} = 5 V, I_C = 10 mA.

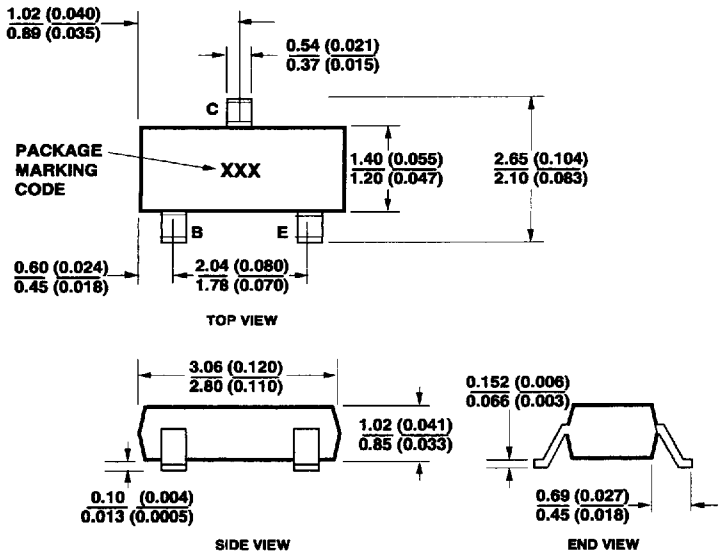
HEWLETT® PACKARD

Ordering Information

Part Number	Increment	Comments
AT-31011-BLK	100	Bulk
AT-31011-TR1	3000	7" Reel
AT-31033-BLK	100	Bulk
AT-31033-TR1	3000	7" Reel

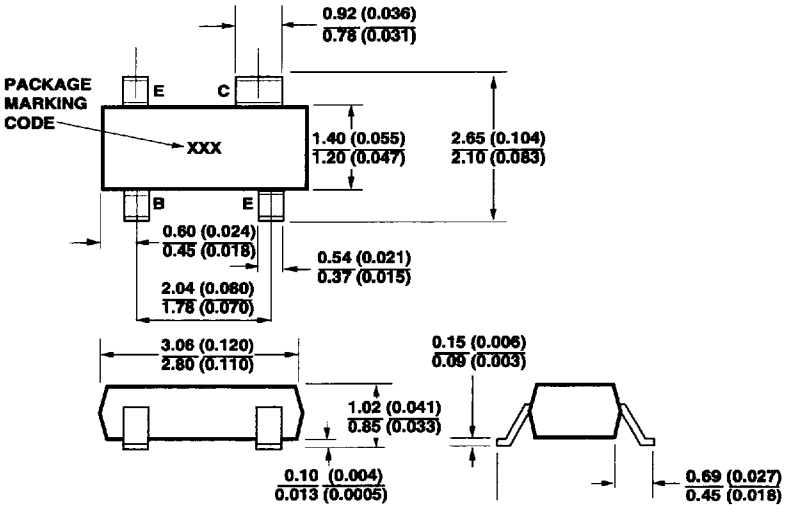
Package Dimensions

SOT-23 Plastic Package



DIMENSIONS ARE IN MILLIMETERS (INCHES)

SOT-143 Plastic Package



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